Zener ESD Protection Diode

SOT−23 Dual Common Anode Zeners for ESD Protection

MA3075WALT1G, SZMA3075WALT1G

These dual monolithic silicon zener diodes are designed for applications requiring transient overvoltage protection capability. They are intended for use in voltage and ESD sensitive equipment such as computers, printers, business machines, communication systems, medical equipment and other applications. Their dual junction common anode design protects two separate lines using only one package. These devices are ideal for situations where board space is at a premium.

Features

- SOT−23 Package Allows Two Separate Unidirectional Configurations
- Low Leakage < 1 μA @ 5.0 V
- Breakdown Voltage: 7.2−7.9 V @ 5 mA
- Low Capacitance (80 pF typical @ 0 V, 1 MHz)
- ESD Protection Meeting: 16 kV Human Body Model
  30 kV Air and Contact Discharge
- SZ Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC−Q101 Qualified and PPAP Capable
- These Devices are Pb−Free, Halogen Free/BFR Free and are RoHS Compliant

Mechanical Characteristics:

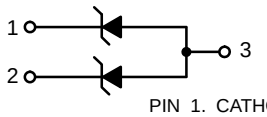
- Void Free, Transfer−Molded, Thermosetting Plastic Case
- Corrosion Resistant Finish, Easily Solderable
- Package Designed for Optimal Automated Board Assembly
- Small Package Size for High Density Applications

MAXIMUM RATINGS

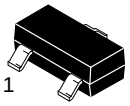
Rating	Symbol	Value	Unit
Peak Power Dissipation @ 100 μs (Note 2)	P_{pk}	15	W
Steady State Power Dissipation Derate above 25°C (Note 3)	P_D	225 1.8	mW mW/°C
Thermal Resistance, Junction−to−Ambient	$R_{\theta JA}$	556	°C/W
Maximum Junction Temperature	$R_{\theta JA}$	417	°C/W
Operating Junction and Storage Temperature Range	T_J, T_{stg}	− 55 to +150	°C
ESD Discharge MIL STD 883C − Method 3015−6 IEC61000−4−2, Air Discharge IEC61000−4−2, Contact Discharge	V_{PP}	 16 30 30	kV

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

2. Non−repetitive 100 μs pulse width
3. Mounted on FR−5 Board = 1.0 X 0.75 X 0.062 in.

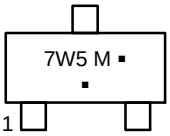


PIN 1. CATHODE
2. CATHODE
3. ANODE



SOT−23
CASE 318
STYLE 12

MARKING DIAGRAM



7W5 = Specific Device Code
M = Date Code*
▪ = Pb−Free Package

(Note: Microdot may be in either location)

*Date Code orientation and/or overbar may vary depending upon manufacturing location.

ORDERING INFORMATION

Device	Package	Shipping†
MA3075WALT1G	SOT−23 (Pb−Free)	3000 / Tape & Reel

DISCONTINUED (Note 1)

SZMA3075WALT1G	SOT−23 (Pb−Free)	3000 / Tape & Reel

†For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

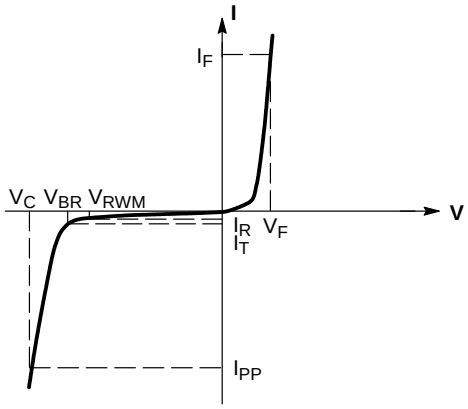
1. **DISCONTINUED:** This device is not recommended for new design. Please contact your **onsemi** representative for information. The most current information on this device may be available on www.onsemi.com.

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ELECTRICAL CHARACTERISTICS

Parameter	Symbol	Conditions	Min	Typ	Max	Unit
Forward Voltage	V_F	I_F = 10 mA		0.8	0.9	V
Zener Voltage*2	V_Z	I_Z = 5 mA	7.2	7.5	7.9	V
Operating Resistance	R_{ZK}	I_Z = 0.5 mA			120	Ω
	R_Z	I_Z = 5 mA		6	15	Ω
Reverse Current	I_{R1}	V_R = 5 V			1	μA
	I_{R2}	V_R = 6.5 V			60	μA
Temperature Coefficient of Zener Voltage*3	S_Z	I_Z = 5 mA	2.5	4.0	5.3	mV/°C
Terminal Capacitance	C_t	V_R = 0 V		80		pF

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.



Uni−Directional

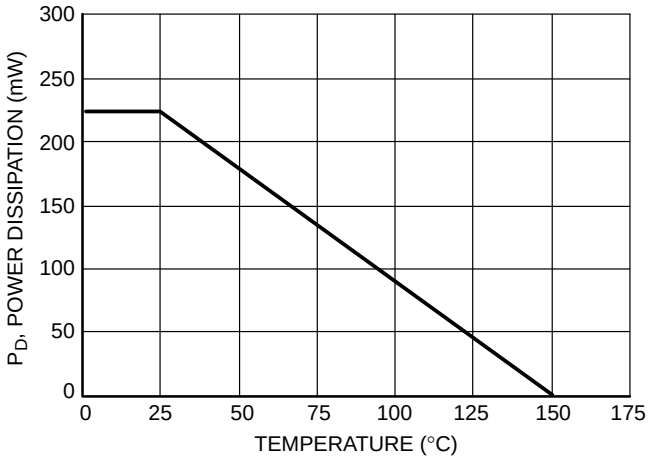


Figure 1. Steady State Power Derating Curve

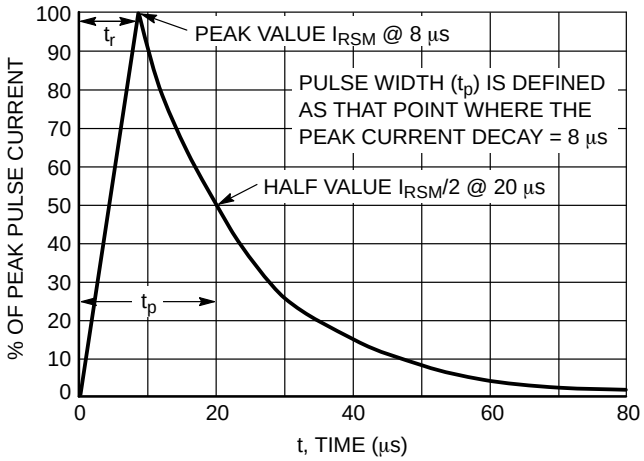


Figure 2. 8 X 20 μs Pulse Waveform

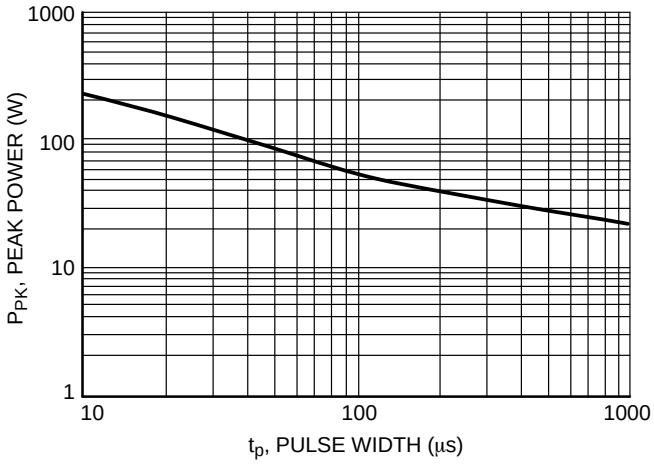


Figure 3. Pulse Rating Curve

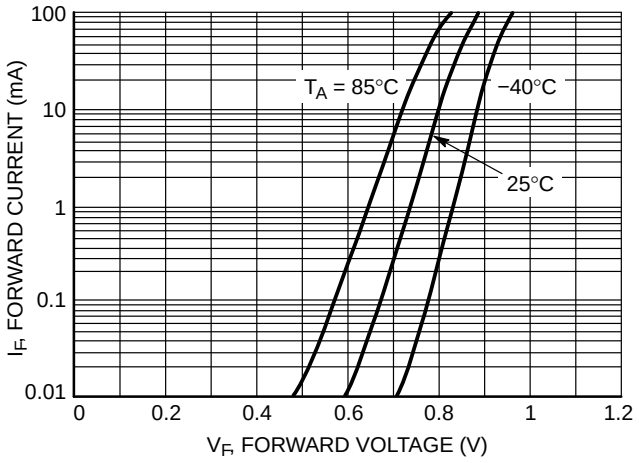


Figure 4. Forward Current versus Forward Voltage

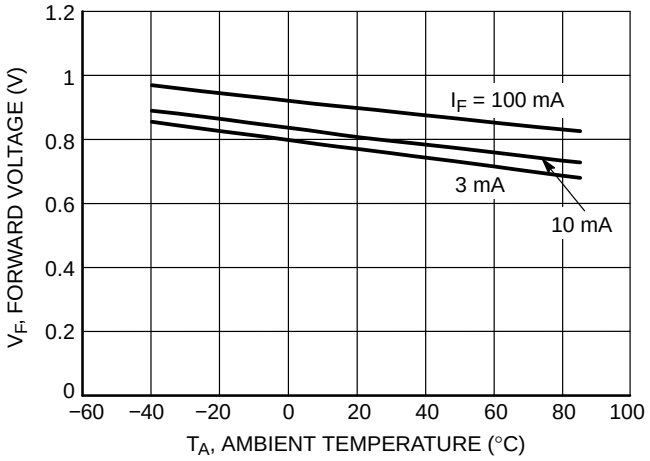


Figure 5. Forward Voltage versus Temperature

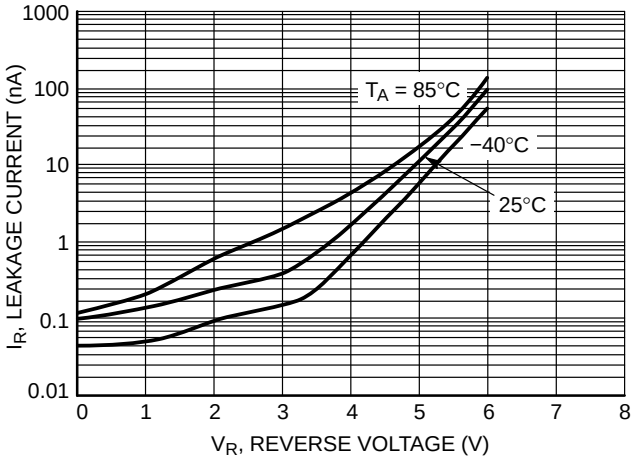


Figure 6. Leakage Current versus Reverse Voltage

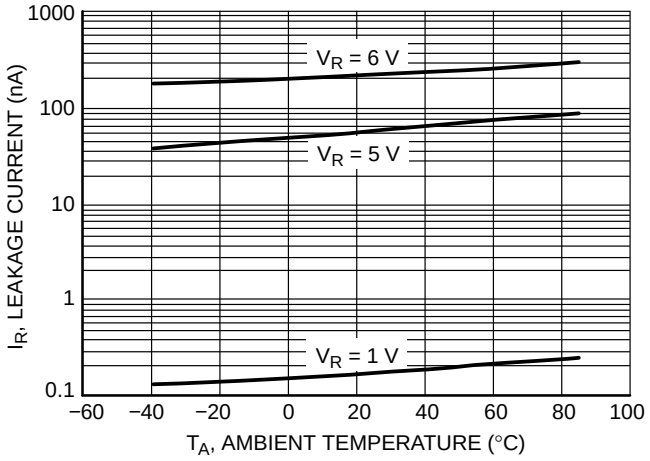


Figure 7. Leakage Current versus Temperature

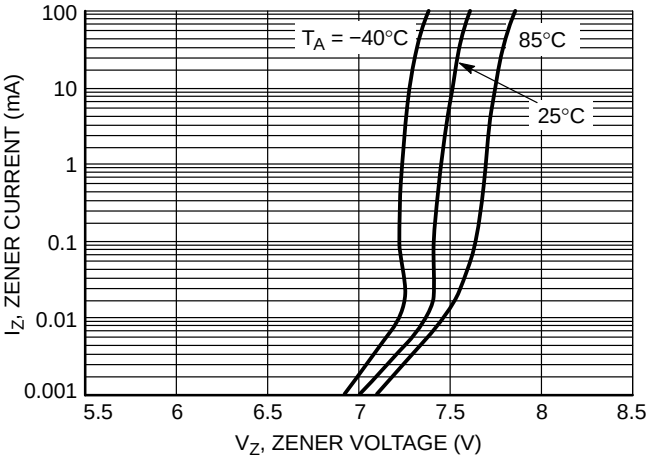


Figure 8. Zener Current versus Zener Voltage

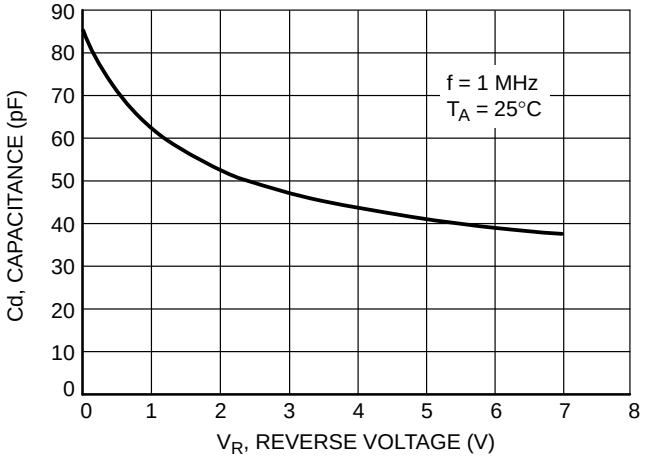


Figure 9. Capacitance

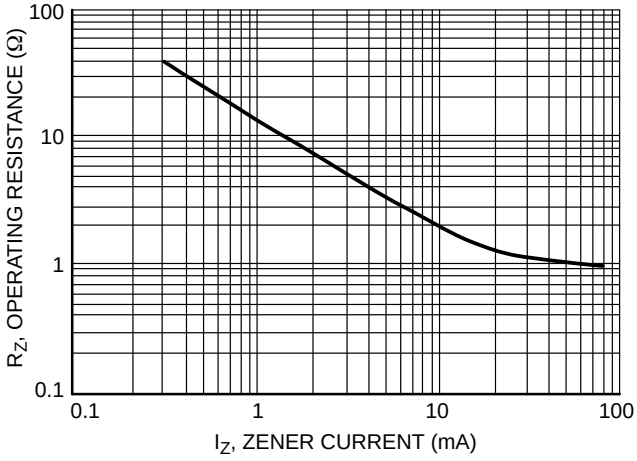
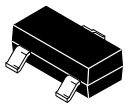


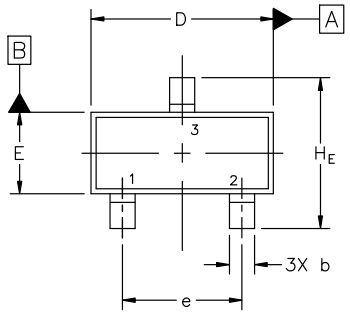
Figure 10. Operating Resistance versus Zener Current



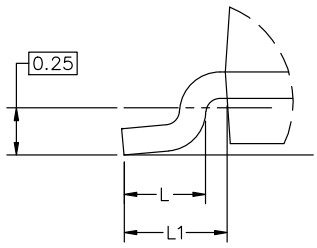
SCALE 4:1

SOT−23 (TO−236) 2.90x1.30x1.00 1.90P
CASE 318
ISSUE AU

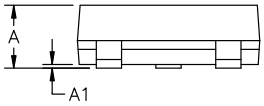
DATE 14 AUG 2024



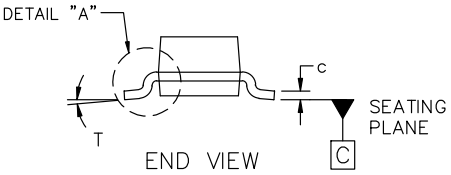
TOP VIEW



DETAIL "A"
Scale 3:1



SIDE VIEW

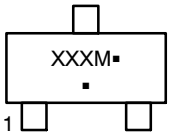


END VIEW

MILLIMETERS			
DIM	MIN	NOM	MAX
A	0.89	1.00	1.11
A1	0.01	0.06	0.10
b	0.37	0.44	0.50
c	0.08	0.14	0.20
D	2.80	2.90	3.04
E	1.20	1.30	1.40
e	1.78	1.90	2.04
L	0.30	0.43	0.55
L1	0.35	0.54	0.69
H_E	2.10	2.40	2.64
T	0°	−−−	10°

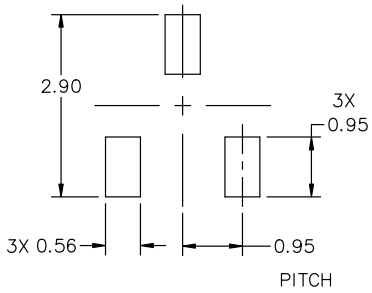
NOTES:
1. DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 2018.
2. CONTROLLING DIMENSIONS: MILLIMETERS.
3. MAXIMUM LEAD THICKNESS INCLUDES LEAD FINISH. MINIMUM LEAD THICKNESS IS THE MINIMUM THICKNESS OF THE BASE MATERIAL.
4. DIMENSIONS D AND E DO NOT INCLUDE MOLD FLASH, PROTRUSIONS, OR GATE BURRS.

GENERIC
MARKING DIAGRAM*



XXX = Specific Device Code
M = Date Code
▪ = Pb−Free Package

*This information is generic. Please refer to device data sheet for actual part marking. Pb−Free indicator, "G" or microdot "▪", may or may not be present. Some products may not follow the Generic Marking.



RECOMMENDED
MOUNTING FOOTPRINT

* For additional information on our Pb−Free strategy and soldering details, please download the onsemi Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

STYLES ON PAGE 2

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DESCRIPTION:	**SOT−23 (TO−236) 2.90x1.30x1.00 1.90P**		**PAGE 1 OF 2**

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CASE 318
ISSUE AU

DATE 14 AUG 2024

STYLE 1 THRU 5:
CANCELLED

STYLE 6:
PIN 1. BASE
2. EMITTER
3. COLLECTOR

STYLE 7:
PIN 1. EMITTER
2. BASE
3. COLLECTOR

STYLE 8:
PIN 1. ANODE
2. NO CONNECTION
3. CATHODE

STYLE 9:
PIN 1. ANODE
2. ANODE
3. CATHODE

STYLE 10:
PIN 1. DRAIN
2. SOURCE
3. GATE

STYLE 11:
PIN 1. ANODE
2. CATHODE
3. CATHODE−ANODE

STYLE 12:
PIN 1. CATHODE
2. CATHODE
3. ANODE

STYLE 13:
PIN 1. SOURCE
2. DRAIN
3. GATE

STYLE 14:
PIN 1. CATHODE
2. GATE
3. ANODE

STYLE 15:
PIN 1. GATE
2. CATHODE
3. ANODE

STYLE 16:
PIN 1. ANODE
2. CATHODE
3. CATHODE

STYLE 17:
PIN 1. NO CONNECTION
2. ANODE
3. CATHODE

STYLE 18:
PIN 1. NO CONNECTION
2. CATHODE
3. ANODE

STYLE 19:
PIN 1. CATHODE
2. ANODE
3. CATHODE−ANODE

STYLE 20:
PIN 1. CATHODE
2. ANODE
3. GATE

STYLE 21:
PIN 1. GATE
2. SOURCE
3. DRAIN

STYLE 22:
PIN 1. RETURN
2. OUTPUT
3. INPUT

STYLE 23:
PIN 1. ANODE
2. ANODE
3. CATHODE

STYLE 24:
PIN 1. GATE
2. DRAIN
3. SOURCE

STYLE 25:
PIN 1. ANODE
2. CATHODE
3. GATE

STYLE 26:
PIN 1. CATHODE
2. ANODE
3. NO CONNECTION

STYLE 27:
PIN 1. CATHODE
2. CATHODE
3. CATHODE

STYLE 28:
PIN 1. ANODE
2. ANODE
3. ANODE

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